NSN 5961-00-147-4482

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-147-4482 **Inclosure Material:** Ceramic **Overall Length:** 0.722 inches **Terminal Length:** 0.100 inches **Overall Height:** 0.200 inches **Overall Width:** 0.300 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-116 **Component Name And Quantity:** 16 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 50.0 working peak reverse voltage all semiconductor device diode **Current Rating Per Characteristic:** 350.00 milliamperes source cutoff current preset all semiconductor device diode **Power Rating Per Characteristic:** 650.0 milliwatts small-signal input power, common-collector absolute all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: